



为您的产品保驾护航

PRODUCT DATASHEET

Electro-Static Discharge

JEN1006-9V-C ESD

Features

- Ultra small package: 1.0x0.6x0.50mm(DFN1006)
- Protects one data or power line
- Ultra low leakage: nA level
- Operating voltage: 9V
- Low clamping voltage
- 2-pin leadless package
- Complies with following standards:
 - IEC 61000-4-2 (ESD) immunity test
Air discharge: $\pm 30\text{kV}$
Contact discharge: $\pm 25\text{kV}$
 - IEC61000-4-5 (Lightning) 5A (8/20 μs)
- RoHS Compliant

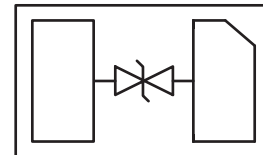
Pin Description



Applications

- Cellular Handsets and Accessories
- Personal Digital Assistants
- Notebooks and Handhelds
- Portable Instrumentation
- Digital Cameras
- Peripherals
- Audio Players
- Keypads, Side Keys, LCD Displays

Schematic Diagram



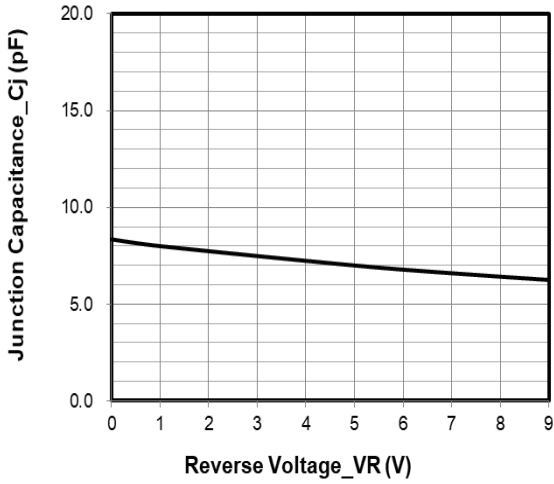
Limiting Values($T_A = 25\text{ }^\circ\text{C}$, unless otherwise specified)

Symbol	Parameter	Conditions	Min	Max	Unit
V _{ESD}	Electrostatic Discharge Voltage	IEC 61000-4-2;Contact Discharge	-	± 25	kV
		IEC 61000-4-2;Air Discharge	-	± 30	kV
P _{PP}	Peak Pulse Power	$t_p=8/20\mu\text{s}$	-	100	W
I _{PP}	Peak Pulse Current	$t_p=8/20\mu\text{s}$	-	5	A
T _A	Ambient Temperature Range	-	-55	125	$^\circ\text{C}$
T _{stg}	Storage Temperature Range	-	-55	150	$^\circ\text{C}$

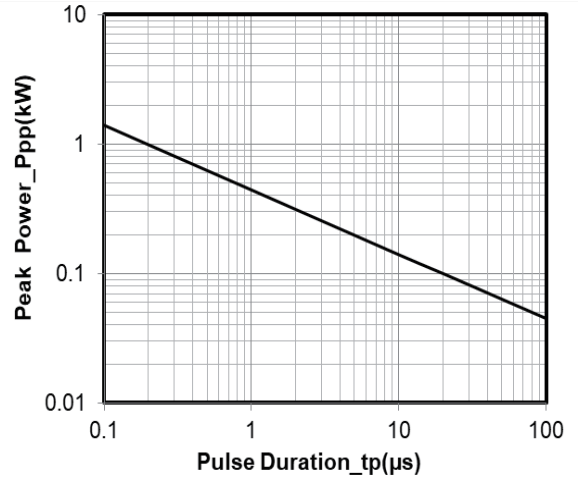
Electrical Characteristics($T_A = 25\text{ }^\circ\text{C}$, unless otherwise specified)

Symbol	Parameter	Conditions	Min	Typ.	Max	Unit
V _{RWM}	Reverse Working Voltage	$T_A=25\text{ }^\circ\text{C}$	-	-	9.0	V
V _{BR}	Breakdown Voltage	$I_R=1\text{mA}; T_A=25\text{ }^\circ\text{C}$	10	-	-	V
I _R	Reverse Leakage Current	$V_{RWM}=9\text{V}; T_A=25\text{ }^\circ\text{C}$	-	-	0.2	μA
V _C	Clamping Voltage	$I_{PP}=1\text{A}$	-	-	14	V
		$I_{PP}=5\text{A}$	-	-	20	V
C _J	Junction Capacitance	$V_R=0\text{V}, f=1\text{MHz}$	-	-	15	pF

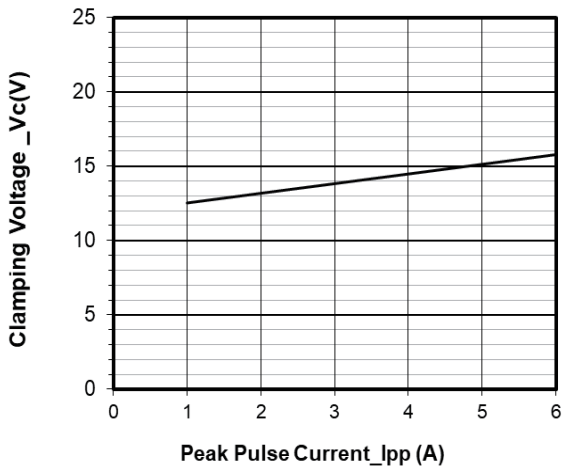
Typical Characteristics



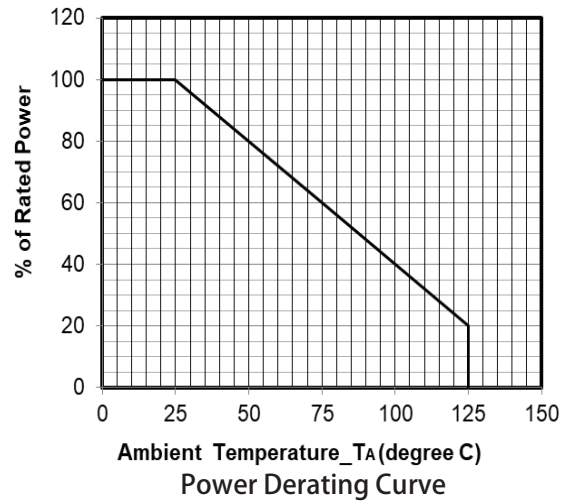
Junction Capacitance vs. Reverse Voltage



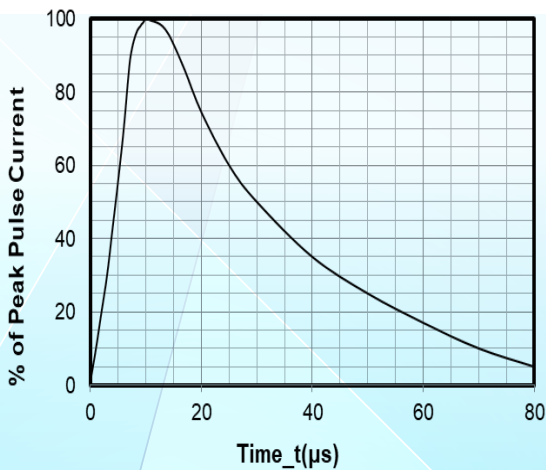
Peak Pulse Power vs. Pulse Time



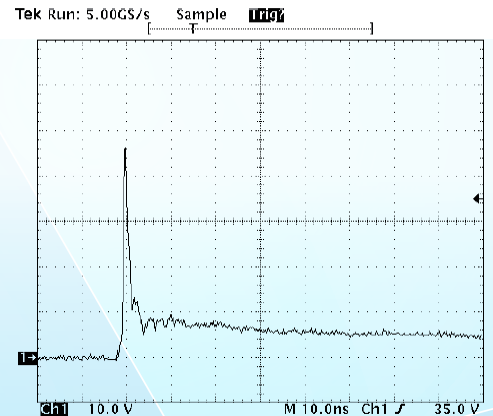
Clamping Voltage vs. Peak Pulse Current (tp = 8/20 μs)



Power Derating Curve

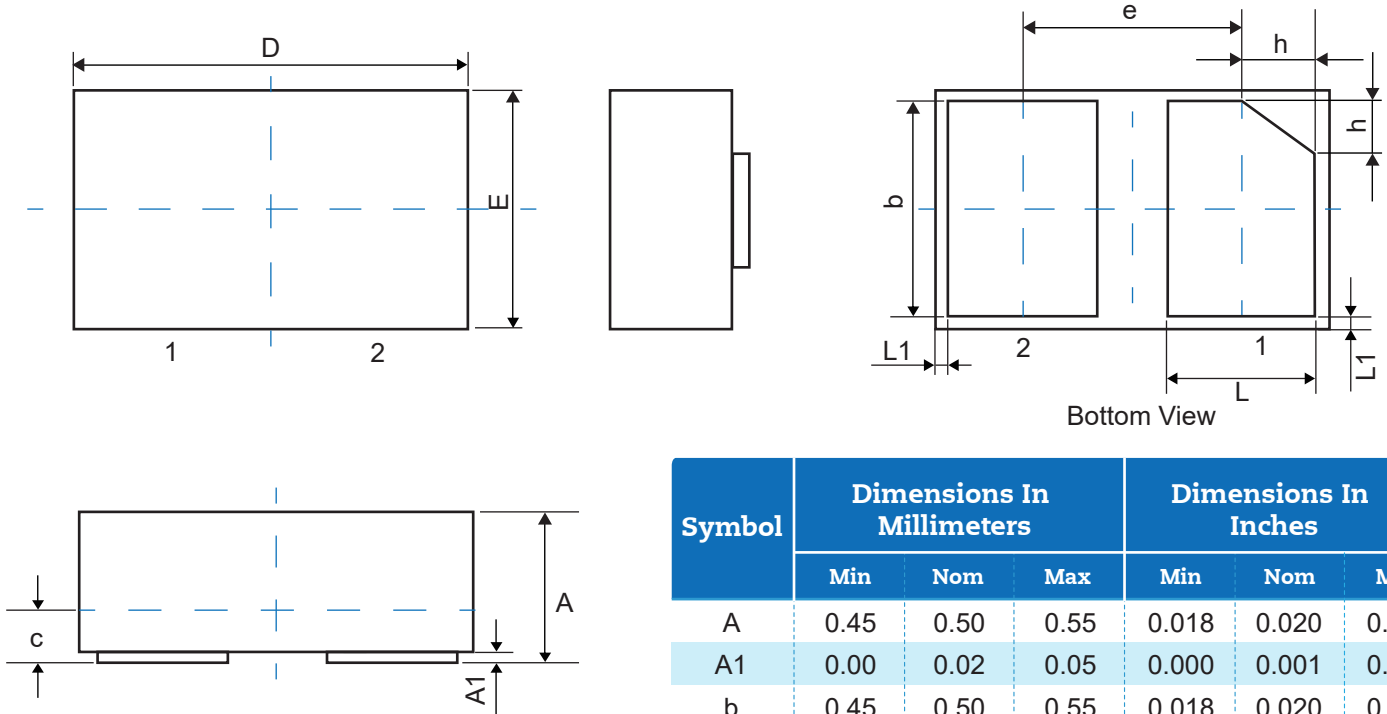


8x20 μs Pulse Waveform



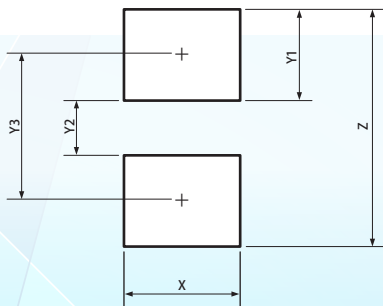
Note: Data is taken with a 10x attenuator
ESD Clamping Voltage
8 kV Contact per IEC61000-4-2

Physical Dimensions(mm.)



Symbol	Dimensions In Millimeters			Dimensions In Inches		
	Min	Nom	Max	Min	Nom	Max
A	0.45	0.50	0.55	0.018	0.020	0.022
A1	0.00	0.02	0.05	0.000	0.001	0.002
b	0.45	0.50	0.55	0.018	0.020	0.022
c	0.12	0.15	0.18	0.005	0.006	0.007
D	0.95	1.00	1.05	0.037	0.039	0.041
e	0.65 BSC			0.026 BSC		
E	0.55	0.60	0.65	0.022	0.024	0.026
L	0.20	0.25	0.30	0.008	0.010	0.012
L1	0.05 REF			0.002 REF		
h	0.07	0.12	0.17	0.003	0.005	0.007

Suggested Land Pattern

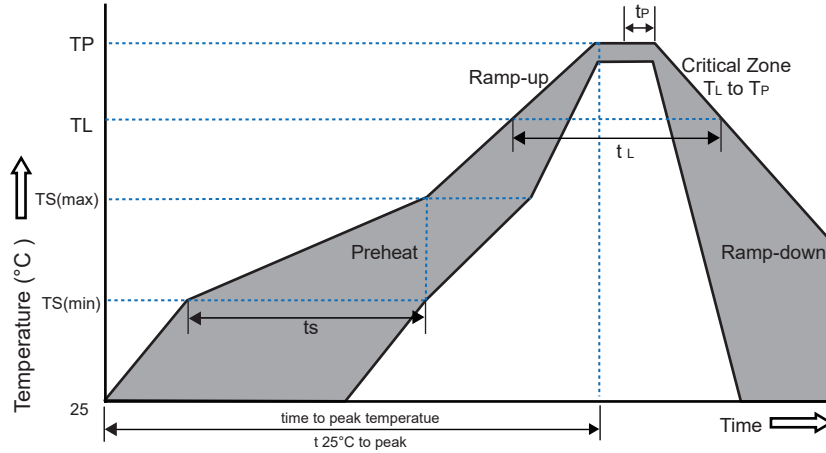


Symbol	Dimensions	
	Millimeters	Inches
X	0.60	0.024
Y1	0.50	0.020
Y2	0.30	0.012
Y3	0.80	0.032
Z	1.30	0.052

Packaging Quantity

Part Number	Size(mm)	Delivery Form	Delivery Quantity
JEN1006-9V-C	1.00x0.60x0.37	7" T&R	10,000

Soldering Parameters



Reflow Condition		Pb-Free Assembly
Pre-heat	-Temperature Min($T_{s(min)}$)	+150°C
	-Temperature Max($T_{s(max)}$)	+200°C
	-Time(Min to Max)(t_s)	60~180 secs.
Average ramp up rate (Liquid us Temp(T_L) to peak)		3°C/sec. Max
Ts(max) to T_L - Ramp-up Rate		3°C/sec. Max
Reflow	-Temperature(T_L)(Liquid us)	+217°C
	-Temperature (t_L)	60~150 secs.
Peak Temp (T_p)		+260(+0/-5)°C
Time within 5°C of actual Peak Temp (t_p)		30 secs. Max
Ramp-down Rate		6°C/sec. Max
xTime 25°C to Peak Temp (TP)		8 min. Max
Do not exceed		+260°C

Part Number System

JE N1006 - 9V - C

